SGM8252A 2.8MHz, High Voltage, High Precision, Low Noise SGMICRO Rail-to-Rail Output Operational Amplifier

GENERAL DESCRIPTION

The dual SGM8252A is a rail-to-rail output, low noise and high precision operational amplifier which has low input offset voltage and bias current. It is guaranteed to operate from 4.5V to 36V single supply.

The rail-to-rail output swing provided by the SGM8252A makes both high-side and low-side sensing easy. The combination of these characteristics makes the SGM8252A a good choice for temperature, position and pressure sensors, medical equipment and strain gauge amplifiers, or any other 4.5V to 36V applications requiring precision and long term stability.

The dual SGM8252A is available in Green SOIC-8 and MSOP-8 packages. It is rated over the -40°C to +125°C temperature range.

FEATURES

- Low Offset Voltage: 18µV (MAX)
- Rail-to-Rail Output Swing
- 4.5V to 36V Single Supply Operation
- Open-Loop Voltage Gain: 150dB (TYP)
- PSRR: 150dB (TYP)
- CMRR: 135dB (TYP)
- 0.1Hz to 10Hz Noise: 0.4µV_{P-P}
- Input Voltage Noise Density: 20nV/ $\sqrt{_{Hz}}~$ at 1kHz
- Gain-Bandwidth Product: 2.8MHz
- Low Supply Current: 450µA/Amplifier (TYP)
- Overload Recovery Time: 3µs
- -40°C to +125°C Operating Temperature Range
- Available in Green SOIC-8 and MSOP-8 Packages

APPLICATIONS

Temperature Measurements Pressure Sensors Precision Current Sensing Electronic Scales Strain Gauge Amplifiers Medical Instrumentation Thermocouple Amplifiers Handheld Test Equipment



SGM8252A

PACKAGE/ORDERING INFORMATION

| MODEL | PACKAGE DESCRIPTION | SPECIFIED TEMPERATURE RANGE | ORDERING NUMBER | PACKAGE MARKING | PACKING OPTION |
|----------|------------------------|-----------------------------------|--------------------|---------------------------|---------------------|
| SGM8252A | SOIC-8 | -40°C to +125°C | SGM8252AXS8G/TR | SGM 8252AXS8 XXXXX | Tape and Reel, 4000 |
| | MSOP-8 | -40°C to +125°C | SGM8252AXMS8G/TR | SGM8252A XMS8 XXXXX | Tape and Reel, 4000 |

MARKING INFORMATION

NOTE: XXXXX = Date Code and Vendor Code.

SOIC-8/MSOP-8



Vendor Code

------ Date Code - Week

----- Date Code - Year

Green (RoHS & HSF): SG Micro Corp defines "Green" to mean Pb-Free (RoHS compatible) and free of halogen substances. If you have additional comments or questions, please contact your SGMICRO representative directly.

ABSOLUTE MAXIMUM RATINGS

| Supply Voltage | 40V |
|----------------------------------|--|
| Input Voltage Range (| $-V_{\rm S}$) - 0.3V to (+V _S) + 0.3V |
| Differential Input Voltage Range | 5V to 5V |
| Junction Temperature | +150°C |
| Storage Temperature Range | 65°C to +150°C |
| Lead Temperature (Soldering, 10s | s)+260°C |
| ESD Susceptibility | |
| HBM | 6000V |
| MM | |
| CDM | 1000V |

RECOMMENDED OPERATING CONDITIONS

Operating Voltage Range4.5V to 36V Operating Temperature Range-40°C to +125°C Differential Input Voltage Range-0.7V to 0.7V

OVERSTRESS CAUTION

Stresses beyond those listed in Absolute Maximum Ratings may cause permanent damage to the device. Exposure to absolute maximum rating conditions for extended periods may affect reliability. Functional operation of the device at any conditions beyond those indicated in the Recommended Operating Conditions section is not implied.

ESD SENSITIVITY CAUTION

This integrated circuit can be damaged by ESD if you don't pay attention to ESD protection. SGMICRO recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage. ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

DISCLAIMER

SG Micro Corp reserves the right to make any change in circuit design, or specifications without prior notice.

PIN CONFIGURATIONS



ELECTRICAL CHARACTERISTICS

(At $T_A = +25^{\circ}$ C, $V_S = \pm 2.5$ V to $V_S = \pm 18$ V, $V_{CM} = 0$ V and $R_L = 10k\Omega$ connected to 0V, Full = -40°C to +125°C, unless otherwise noted.)

| PARAMETER | CONDITIONS | TEMP | MIN | TYP | MAX | UNITS |
|--|--|-------|---------------------------|--------|-------------------------|---------------|
| Input Characteristics | • | | | | | |
| | | +25°C | | 5 | 18 | |
| | | Full | | | 20 | μν |
| Input Offset Voltage Drift (ΔV _{os} /ΔT) | | Full | | 20 | | nV/°C |
| Input Bias Current (I _B) | | +25°C | | ±100 | ±400 | pА |
| Input Offset Current (I _{os}) | | +25°C | | ±200 | ±600 | pА |
| Input Common Mode Voltage Range (V _{CM}) | | Full | (-V _S) - 0.05 | | (+V _s) -1.5 | V |
| | | +25°C | 115 | 135 | | 10 |
| Common Mode Rejection Ratio (CMRR) | $V_{CM} = (-V_S) - 0.05V$ to $(+V_S) - 1.5V$ | Full | 112 | | | dВ |
| | | +25°C | 118 | 140 | | |
| | $V_{\rm S} = \pm 2.5 V, V_{\rm OUT} = \pm 2.0 V$ | Full | 115 | | | |
| Open-Loop Voltage Gain (A _{OL}) | | +25°C | 128 | 150 | | dВ |
| | $V_{\rm S} = \pm 18V, V_{\rm OUT} = \pm 17.5V$ | Full | 125 | | | |
| Output Characteristics | | | | | | |
| Output Voltage Swing from Rail | | +25°C | | 12 | 25 | |
| | $V_{\rm S} = \pm 2.5 V$ | Full | | | 30 | |
| | | +25°C | | 95 | 140 | mV |
| | $V_{\rm S} = \pm 18V$ | Full | | | 200 | 1 |
| | | +25°C | ±20 | ±32 | | |
| | $V_{\rm S} = \pm 2.5 V$ | Full | ±11 | | | - mA |
| Output Short-Circuit Current (I _{sc}) | | +25°C | ±38 | ±50 | | |
| | $V_{\rm S} = \pm 18V$ | Full | ±18 | | | |
| Power Supply | | | | | | |
| Operating Voltage Range (V _s) | | Full | 4.5 | | 36 | V |
| | | +25°C | | 450 | 660 | |
| Quiescent Current/Amplifier (I _Q) | $I_{OUT} = 0$ | Full | | | 750 | μA |
| | | +25°C | 128 | 150 | | |
| Power Supply Rejection Ratio ⁽¹⁾ (PSRR) | V _s = 4.5V to 36V | Full | 125 | | | dB |
| Dynamic Performance | | | | | | |
| Gain-Bandwidth Product (GBP) | $V_{OUT} = 100 m V_{P-P}, C_L = 10 p F$ | +25°C | | 2.8 | | MHz |
| Slew Rate (SR) | | +25°C | | 1.3 | | V/µs |
| Settling Time to 0.1% (t _s) | V _{IN} = 1V Step, A _V = +1 | +25°C | | 0.8 | | μs |
| Overload Recovery Time | $V_{IN} \times A_V > V_S$ | +25°C | | 3 | | μs |
| Total Harmonic Distortion + Noise (THD+N) | $V_{IN} = 2V_{P-P}, A_V = +1, f = 1kHz$ | +25°C | | 0.0002 | | % |
| Noise | | | | | | |
| Input Voltage Noise | f = 0.1Hz to 10Hz | +25°C | | 0.4 | | μV_{P-P} |
| | f = 0.1kHz | +25°C | | 20 | | |
| Input Voltage Noise Density (e _n) | f = 1kHz | +25°C | | 20 | | nV/√Hz |
| | f = 10kHz | +25°C | | 23 | | |

NOTE: 1. PSRR and CMRR are affected by the matching between external gain-setting resistor ratios.



TYPICAL PERFORMANCE CHARACTERISTICS

At T_A = +25°C, V_S = ±15V, C_L = 10pF and R_L = 10k Ω , unless otherwise noted.



TYPICAL PERFORMANCE CHARACTERISTICS (continued)

At T_A = +25°C, V_S = ±15V, C_L = 10pF and R_L = 10k Ω , unless otherwise noted.



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TYPICAL PERFORMANCE CHARACTERISTICS (continued)

At T_A = +25°C, V_S = ±15V, C_L = 10pF and R_L = 10k Ω , unless otherwise noted.



TYPICAL PERFORMANCE CHARACTERISTICS (continued)

At T_A = +25°C, V_S = ±15V, C_L = 10pF and R_L = 10k Ω , unless otherwise noted.



APPLICATION NOTES

Driving Capacitive Loads

The unity-gain follower (buffer) is the most sensitive configuration to capacitive loading. Direct capacitive loading reduces the phase margin of amplifiers and this results in ringing or even oscillation. Applications that require greater capacitive driving capability should use an isolation resistor between the output and the capacitive load like the circuit in Figure 1. The isolation resistor R_{ISO} and the load capacitor C_L form a zero to increase stability. The bigger the R_{ISO} resistor value, the more stable V_{OUT} will be. Note that this method results in a loss of gain accuracy because R_{ISO} forms a voltage divider with the R_{LOAD}.



Figure 1. Indirectly Driving Heavy Capacitive Load

An improved circuit is shown in Figure 2. It provides DC accuracy as well as AC stability. R_F provides the DC accuracy by connecting the inverting input with the output. C_F and R_{ISO} serve to counteract the loss of phase margin by feeding the high frequency component of the output signal back to the amplifier's inverting input, thereby preserving phase margin in the overall feedback loop.



Figure 2. Indirectly Driving Heavy Capacitive Load with DC Accuracy

For non-buffer configuration, there are two other ways to increase the phase margin: (a) by increasing the amplifier's closed-loop gain or (b) by placing a capacitor in parallel with the feedback resistor to counteract the parasitic capacitance associated with inverting node.

Power Supply Bypassing and Layout

The SGM8252A operates from either a single 4.5V to 36V supply or dual $\pm 2.25V$ to $\pm 18V$ supplies. For

single-supply operation, bypass the power supply +V_S with a 0.1µF ceramic capacitor which should be placed close to the +V_S pin. For dual-supply operation, both the +V_S and the -V_S supplies should be bypassed to ground with separate 0.1µF ceramic capacitors. 2.2µF tantalum capacitor can be added for better performance.

Good PC board layout techniques optimize performance by decreasing the amount of stray capacitance at the operational amplifier's inputs and output. To decrease stray capacitance, minimize trace lengths and widths by placing external components as close to the device as possible. Use surface-mount components whenever possible.

For the operational amplifier, soldering the part to the board directly is strongly recommended. Try to keep the high frequency current loop area small to minimize the EMI (electromagnetic interference).



Figure 3. Amplifier with Bypass Capacitors

Grounding

A ground plane layer is important for SGM8252A circuit design. The length of the current path in an inductive ground return will create an unwanted voltage noise. Broad ground plane areas will reduce the parasitic inductance.

Input-to-Output Coupling

To minimize capacitive coupling, the input and output signal traces should not be in parallel. This helps reduce unwanted positive feedback.



SGM8252A

TYPICAL APPLICATION CIRCUITS

Differential Amplifier

The circuit shown in Figure 4 performs the difference function. If the resistor ratios are equal $(R_4/R_3 = R_2/R_1)$, then $V_{OUT} = (V_P - V_N) \times R_2/R_1 + V_{REF}$.



Figure 4. Differential Amplifier

Instrumentation Amplifier

The circuit in Figure 5 performs the same function as that in Figure 4 but with a high input impedance.



Figure 5. Instrumentation Amplifier

Active Low-Pass Filter

The low-pass filter shown in Figure 6 has a DC gain of $(-R_2/R_1)$ and the -3dB corner frequency is $1/2\pi R_2 C$. Make sure the filter bandwidth is within the bandwidth of the amplifier. Feedback resistors with large values can couple with parasitic capacitance and cause undesired effects such as ringing or oscillation in high-speed amplifiers. Keep resistor values as low as possible and consistent with output loading consideration.



Figure 6. Active Low-Pass Filter

REVISION HISTORY

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

| Changes from Original (SEPTEMBER 2019) to REV.A | Page |
|---|------|
| Changed from product preview to production data | All |



PACKAGE OUTLINE DIMENSIONS

SOIC-8





RECOMMENDED LAND PATTERN (Unit: mm)





| Symbol | Dimer In Milli | nsions meters | Dimensions In Inches | | |
|--------|-------------------|------------------|-------------------------|-------|--|
| | MIN | MAX | MIN | MAX | |
| A | 1.350 | 1.750 | 0.053 | 0.069 | |
| A1 | 0.100 | 0.250 | 0.004 | 0.010 | |
| A2 | 1.350 | 1.550 | 0.053 | 0.061 | |
| b | 0.330 | 0.510 | 0.013 | 0.020 | |
| С | 0.170 0.250 | | 0.006 | 0.010 | |
| D | 4.700 5.100 | | 0.185 | 0.200 | |
| E | 3.800 | 4.000 | 0.150 | 0.157 | |
| E1 | 5.800 | 6.200 | 0.228 | 0.244 | |
| е | 1.27 BSC | | 0.050 | BSC | |
| L | 0.400 1.270 | | 0.016 | 0.050 | |
| θ | 0° 8° | | 0° | 8° | |

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PACKAGE OUTLINE DIMENSIONS

MSOP-8





RECOMMENDED LAND PATTERN (Unit: mm)





| Symbol | Dimer In Milli | nsions meters | Dimensions In Inches | | |
|--------|-------------------|------------------|-------------------------|-------|--|
| | MIN | MAX | MIN | MAX | |
| A | 0.820 | 1.100 | 0.032 | 0.043 | |
| A1 | 0.020 | 0.150 | 0.001 | 0.006 | |
| A2 | 0.750 | 0.950 | 0.030 | 0.037 | |
| b | 0.250 | 0.380 | 0.010 | 0.015 | |
| С | 0.090 | 0.230 | 0.004 | 0.009 | |
| D | 2.900 | 3.100 | 0.114 | 0.122 | |
| E | 2.900 | 3.100 | 0.114 | 0.122 | |
| E1 | 4.750 | 5.050 | 0.187 | 0.199 | |
| е | 0.650 BSC | | 0.026 | BSC | |
| L | 0.400 0.800 | | 0.016 | 0.031 | |
| θ | 0° 6° | | 0° | 6° | |

TAPE AND REEL INFORMATION

REEL DIMENSIONS



NOTE: The picture is only for reference. Please make the object as the standard.

KEY PARAMETER LIST OF TAPE AND REEL

| Package Type | Reel Diameter | Reel Width W1 (mm) | A0 (mm) | B0 (mm) | K0 (mm) | P0 (mm) | P1 (mm) | P2 (mm) | W (mm) | Pin1 Quadrant |
|--------------|------------------|--------------------------|------------|------------|------------|------------|------------|------------|-----------|------------------|
| SOIC-8 | 13″ | 12.4 | 6.40 | 5.40 | 2.10 | 4.0 | 8.0 | 2.0 | 12.0 | Q1 |
| MSOP-8 | 13″ | 12.4 | 5.20 | 3.30 | 1.50 | 4.0 | 8.0 | 2.0 | 12.0 | Q1 |

CARTON BOX DIMENSIONS



NOTE: The picture is only for reference. Please make the object as the standard.

KEY PARAMETER LIST OF CARTON BOX

| Reel Type | Length (mm) | Width (mm) | Height (mm) | Pizza/Carton |]_ |
|-----------|----------------|---------------|----------------|--------------|-------|
| 13″ | 386 | 280 | 370 | 5 | 00002 |

